



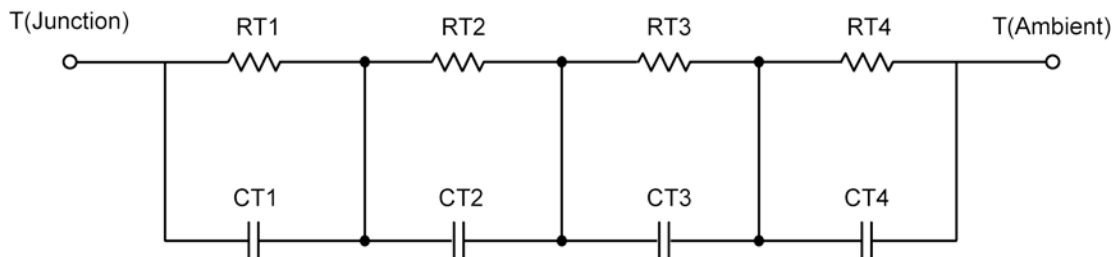
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	14.2502	165.3723 m	N/A
RT2	47.4875	685.2277 m	N/A
RT3	9.2965	1.1888	N/A
RT4	9.9658	1.1606	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	12.4147 m	200.4258 u	N/A
CT2	1.7991	702.5415 u	N/A
CT3	201.4269 m	21.8483 m	N/A
CT4	657.5218 u	8.1922 m	N/A

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	11.4706	725.5945 m	N/A
RF2	13.3952	908.1701 m	N/A
RF3	10.7402	663.0285 m	N/A
RF4	45.3940	903.2069 m	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	661.8381 u	257.9020 u	N/A
CF2	10.8584 m	3.7360 m	N/A
CF3	146.2275 m	188.7966 u	N/A
CF4	1.7110	19.0953 m	N/A

Note: NA indicates not applicable

